


## POWER OF ATTORNEY OR AUTHORIZATION OF AGENT

Electronic Version v05

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<b>Title of Invention</b>	METHOD FOR GROWING A GATE OXIDE LAYER ON A SILICON SURFACE WITH PRELIMINARY N2O ANNEAL
First Named Applicant :	Shian-Jyh Lin
Attorney Docket Number :	NTCP0014USA
I hereby appoint the registered practitioner(s) at Customer Number:	
027765	
as attorney(s) or agent(s) to prosecute the application identified above, and to transact all business in the United States Patent and Trademark Office connected therewith.	
I am the Applicant/Inventor.	
Full Name of Applicant of Record:	
Winston Hsu	
Signature: /Winston Hsu/	Date: 2004-08-28